ψ Edging Component

WS2024: Dual Nano-WO3-Based Gas Sensor with Integrated Micro-heater

Features

- Detection of multiple gases: Ammonia (NH₃), Nitrogen Dioxide (NO₂), and Ethanol (C₂H₆O)
- Two integrated gas sensors
- Integrated temperature sensor (aluminum resistor)
- Integrated thermal resistor (polysilicon heater)
- Compact and cost-effective design
- Low energy consumption
- Easy to integrate and use

Description

The WS2024 gas sensor employs tungsten trioxide (WO $_3$) nanoparticles for detecting various gases with high sensitivity and selectivity. The sensor includes two active sensing areas, interdigitated aluminum comb electrodes, and an integrated n-doped polysilicon microheater for precise temperature control. An aluminum temperature sensor ensures real-time monitoring of the sensing area to optimize performance.

This is a compact and energy-efficient sensor delivers reliable operation across diverse environments. Its robust design supports applications like environmental monitoring, industrial safety, and automotive emissions detection, making it an ideal choice for modern gas sensing needs.

Standard Applications

- Environmental monitoring
- Industrial safety systems
- Automotive emissions detection

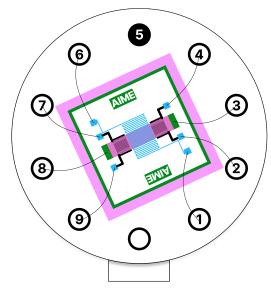


Figure 1: Schematic of the sensor

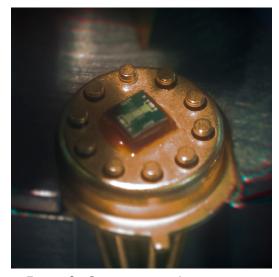


Figure 2: Gas sensor, without covering

Typical Application

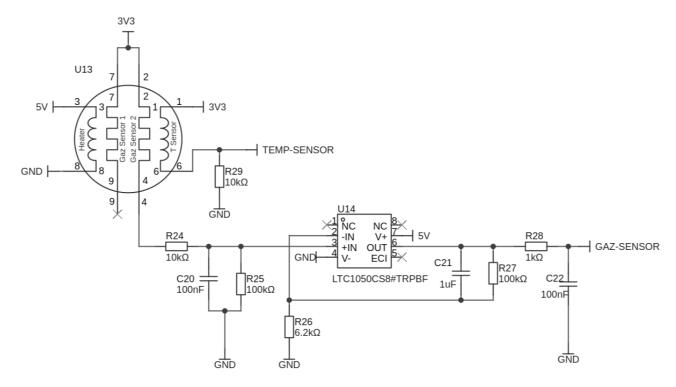


Figure 3: Typical Application

This circuit integrate the gas sensor into a standard amplifying measuring chain for a microcontroller. It is composed of three cascading filter: to filter the high frequency measuring noise, the 50 hz outlet noise and the sampling noise of the ADC. See **Fig. 8** for a typical output from this application.

Pin Configuration

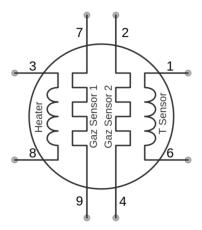


Figure 4: Sensor Pinout

Pin Number	Pin Function		
1 & 2 & 7	3V3		
3	5V		
4	Gas Sensor		
5 & 9 & 10	NC		
6	Temperature Sensor		
8	GND		

Table 1: Pinout of the typical application

Absolute Maximum Ratings

All specifications are in $-40^{\circ}C \leq T_A \leq 85^{\circ}C$ unless otherwise noted.

Table 2: Electronic Specifications

Conditions	Parameter	Symbol	Min.	Тур.	Max.	Unit
	R Aluminium	R_{alu}		90.1		Ohm
Aluminium	D nominal	D_{nom}	0		5	V
	D non degrading	D_{nonDeg}	5		10	V
	R Polysilicon ¹	R_{poly}		79.1		Ohm
Polysilicon	D nominal	D_{nom}	0		5	V
	D non degrading	D_{nonDeg}	5		15	V
	Rcapteur	R_{capt}		20		GOhm

^{*} Based on characterization data only.

Table 3: Sensitivity and Limit, under $N_2 O_2$ first then $CH_3 CH_2 OH$

T(K)	DR/R0(%)	kN2O2-tN202	Sensitivity (Ohm/ppm)	Sensitivity limit (ppm)
550	55.70%	0.008	880000	246.59
T(K)	DR/R0(%)	keth-teth	Sensitivity (Ohm/ppm)	Sensitivity limit (ppm)
550	48.21%	0.007	810000	112.84

 $^{^{1}}$ R_{Poly} is the resistance measured between PINS 1 & 6, acting as sensor measurand

Typical Characteristics

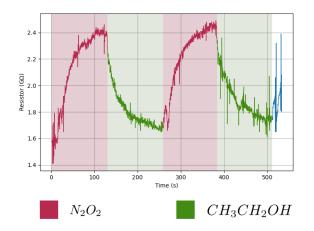


Figure 5: Resistor (in $G\Omega$) depending on the gas

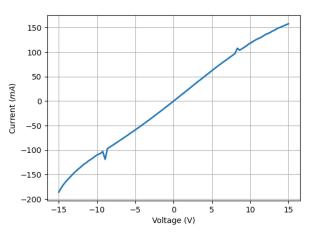


Figure 6: Current of R_{poly} (in mA) depending on the current (in V)

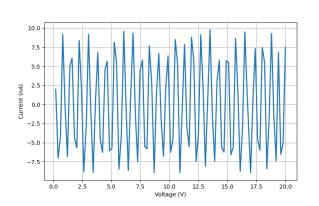


Figure 7: Comb¹'s current (in nA) depending on the given voltage (in V)

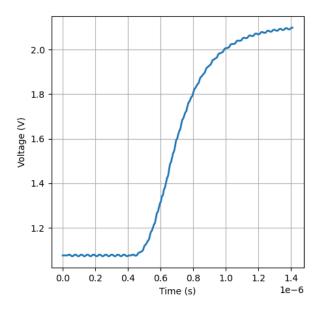
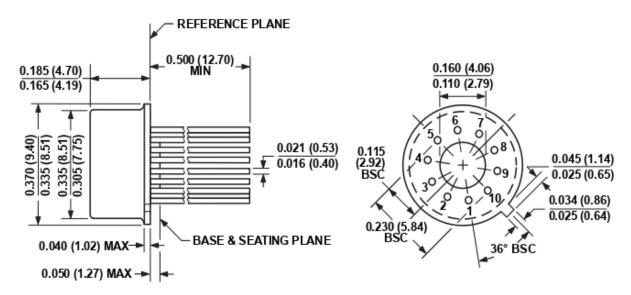


Figure 8: V_{out} from the typical application using $\it LTSpice$

¹Comb: Resistor between pins 7 & 9 or 2 & 4. (see Fig. 1)

Dimensions

ANALOG DEVICES 10-Pin Metal Header Package [TO-100] (H-10-1) Dimensions shown in inches and (millimeters)



DIMENSIONS PER JEDEC STANDARDS MO-006-AF CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 9: TO-100 Package with 10 pins

2306-A